

IXTP110N12T2 Information


For Reference Only

Part Number [IXTP110N12T2](#)
Manufacturer IXYS
Category Discrete Semiconductor Products
[Transistors - FETs, MOSFETs - Single](#)
Description 120V/110A TRENCHT2 POWER MOSFET
Package TO-220-3
 For the pricing/inventory/lead time, please contact us
 Website: <https://www.heisener.com>
 E-mail: salesdept@heisener.com


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Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.


IXTP110N12T2 Specifications

Manufacturer Part Number	IXTP110N12T2
Manufacturer	IXYS
Category	Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single
Package	TO-220-3
Series	TrenchT2?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (V _{ds})	120V
Current - Continuous Drain (I _d) @ 25°C	110A (T _c)
Drive Voltage (Max R _{ds} On, Min R _{ds} On)	10V
V _{gs} (th) (Max) @ I _d	4.5V @ 250μA
Gate Charge (Q _g) (Max) @ V _{gs}	120nC @ 10V
Input Capacitance (C _{iss}) (Max) @ V _{ds}	6570pF @ 25V
V _{gs} (Max)	±20V
FET Feature	-
Power Dissipation (Max)	517W (T _c)
R _{ds} On (Max) @ I _d , V _{gs}	14 mOhm @ 55A, 10V
Operating Temperature	-55°C ~ 175°C (T _J)
Mounting Type	Through Hole
Supplier Device Package	TO-220AB
Package / Case	TO-220-3

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IXTP110N12T2 Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

IXTP110N12T2 Payment Methods



IXTP110N12T2 Shipping Methods



If you have any question about IXTTP110N12T2, please do not hesitate to contact us!

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